

## 128K x 32 SRAM Module

PUMA67S4000/A-45/55/70

Issue 4.0: March 1996

### Description

The PUMA67S4000/A is a 4Mbit CMOS High Speed Static RAM organised as 128k x 32 in a JEDEC J-leaded Ceramic Surface Mount Substrate. The output width is user configurable to 8, 16 or 32 bits and is available with two pinouts, a single WE or version A with WE1-4. Access times available are 45ns, 55ns and 70ns. It has a low power standby of 44mW and is 3.0V battery back-up compatible. All inputs and outputs are TTL compatible.

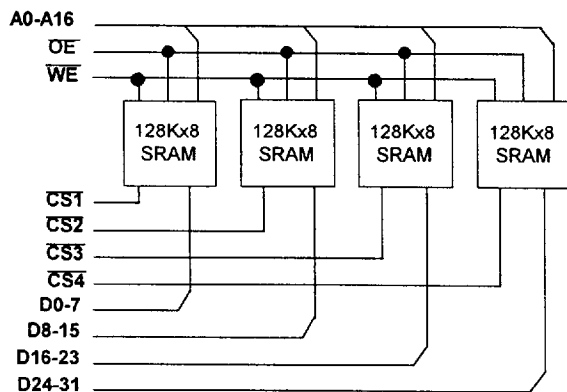
All versions can be screened in accordance with MIL-STD-883 or with BS9400 requirements.

4,194,304 bit CMOS High Speed Static RAM

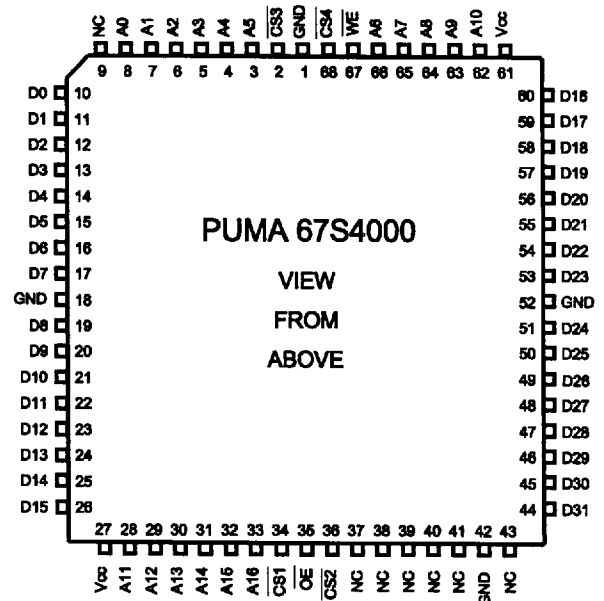
### Features

- Fast Access Times of 45/55/70 ns.
- JEDEC 68 'J' Ceramic Surface Mount Substrate, available in two pinouts: Single WE is standard version, WE1~4 is A version.
- User Configurable as 8 / 16 / 32 bit wide output.
- Operating Power 688 / 1045 / 1760 mW (Max)
- Low Power Standby 44 mW (Max). - L Version
- 3.0V Battery Back-up Capability.
- TTL Compatible Inputs and Outputs.
- Equal Access and Cycle Times.

### Block Diagram (see page 7 for A Block Diagram)



### Pin Definition (see page 7 for A pinout)



### Pin Functions

**A0~A16** Address Inputs

**CS1~4** Chip Selects

**WE** Write Enable (**WE1~4** for A version)

**V<sub>cc</sub>** Power (+5V)

**D0~D31** Data Inputs/Outputs

**OE** Output Enable

**NC** No Connect

**GND** Ground

**DC OPERATING CONDITIONS****Absolute Maximum Ratings** <sup>(1)</sup>

Voltage on any pin relative to $V_{SS}$ <sup>(2)</sup>	$V_T$	-0.5V to +7	V
Power Dissipation	$P_T$	4	W
Storage Temperature	$T_{STG}$	-55 to +150	°C

Notes (1) Stresses above those listed may cause permanent damage. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

(2) Pulse width: -3.0V for less than 20ns.

**Recommended Operating Conditions**

		<i>min</i>	<i>typ</i>	<i>max</i>	
Supply Voltage	$V_{CC}$	4.5	5.0	5.5	V
Input High Voltage	$V_{IH}$	2.2	-	5.8	V
Input Low Voltage	$V_{IL}$	-0.3	-	0.8	V
Operating Temperature	$T_A$	0	-	70	°C
	$T_{AI}$	-40	-	85	°C (Suffix I)
	$T_{AM}$	-55	-	125	°C (Suffix M, MB)

**DC Electrical Characteristics** ( $V_{CC}=5V\pm 10\%$ ,  $T_A=-55^\circ\text{C}$  to  $+125^\circ\text{C}$ )

Parameter	Symbol	Test Condition	<i>min</i>	<i>typ</i> <sup>(1)</sup>	<i>max</i>	Unit
Input Leakage Current Address, $\overline{OE}$ , $\overline{WE}$ CS1~4, WE1~4	$I_{LI1}$	$V_{IN} = 0V$ to $V_{CC}$	-8	-	8	$\mu\text{A}$
	$I_{LI2}$	$V_{IN} = 0V$ to $V_{CC}$	-2	-	2	$\mu\text{A}$
Output Leakage Current	8bit $I_{LO}$	$\overline{CS}^{(2)}=V_{IH}$ , $\overline{OE}=V_{IH}$ or $\overline{WE}=V_{IL}$ , $V_{I/O}=0V$ to $V_{CC}$	-8	-	8	$\mu\text{A}$
Operating Supply Current	32bit $I_{CC32}$	$\overline{CS}^{(2)}=V_{IL}$ , $I_{I/O}=0\text{mA}$ , I/P's static	-	-	320	mA
	16bit $I_{CC16}$	As above	-	-	190	mA
	8bit $I_{CC8}$	As above	-	-	125	mA
Average Supply Current	32bit $I_{CC32}$	Min. cycle, $I_{I/O}=0\text{mA}$ , 100% Duty	-	-	480	mA
	16bit $I_{CC16}$	As above	-	-	270	mA
	8bit $I_{CC8}$	As above	-	-	165	mA
Standby Supply Current	TTL levels $I_{SB}$	$\overline{CS}^{(2)}=V_{IH}$	-	-	60	mA
	-L Version $I_{SB1}$	$\overline{CS}^{(2)}\geq V_{CC}-0.2V$ , $V_{IN}=V_{IH}$ or $V_{IL}$ , Min. cycle	-	0.04	8	mA
Output Voltage Low	$V_{OL}$	$I_{OL}=8.0\text{mA}$	-	-	0.4	V
Output Voltage High	$V_{OH}$	$I_{OH}=-4.0\text{mA}$	2.4	-	-	V

Notes: (1) Typical values are at  $V_{CC}=5.0V$ ,  $T_A=25^\circ\text{C}$  and specified loading.

(2) CS above is accessed through CS1~4 (and WE is accessed by WE1~4 on the PUMA 67S4000A), and these inputs must be controlled as required by the user.

**Capacitance** ( $V_{CC}=5V\pm 10\%$ ,  $T_A=25^\circ\text{C}$ )

Parameter	Symbol	Test Condition	<i>typ</i>	<i>max</i>	Unit
Input Capacitance Address, $\overline{OE}$ WE1~4 <sup>(1)</sup> , CS1~4	$C_{IN1}$	$V_{IN}=0V$	-	38	pF
	$C_{IN2}$	$V_{IN}=0V$	-	17	pF
I/O Capacitance	D0~D31 $C_{I/O}$	$V_{I/O}=0V$	-	38	pF

These parameters are calculated, not measured.

Note: (1) On the standard module  $\overline{WE} = 38\text{pF}$  max.

**Operating Modes**

The Table below shows the logic inputs required to control the operating modes of each of the SRAMs on the PUMA 67S4000 or PUMA 67S4000A modules.

Mode	$\overline{CS}$	$\overline{OE}$	$\overline{WE}$	$V_{CC}$ Current	I/O Pin	Reference Cycle
Not Selected	1	X	X	$I_{SB}, I_{SB1}$	High Z	Power Down
Output Disable	0	1	1	$I_{CC}$	High Z	
Read	0	0	1	$I_{CC}$	$D_{OUT}$	Read Cycle
Write	0	X	0	$I_{CC}$	$D_{IN}$	Write Cycle

1 =  $V_{IH}$ ,  
 0 =  $V_{IL}$ ,  
 X = Don't Care

Note:  $\overline{CS}$  above is accessed through  $\overline{CS1-4}$  (and  $\overline{WE}$  by  $\overline{WE1-4}$  on the PUMA 67S4000A). For correct operation,  $\overline{CS1-4}$  (and  $\overline{WE1-4}$ ) must operate simultaneously for 32 bit operation, in pairs for 16 bit operation, or singly for 8 bit operation.

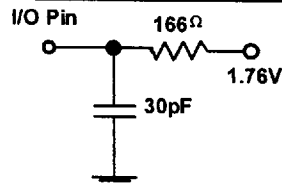
**Low  $V_{CC}$  Data Retention Characteristics - L Version Only ( $T_A = -55^\circ C$  to  $+125^\circ C$ )**

Parameter	Symbol	Test Condition	min	typ	max	Unit
$V_{CC}$ for Data Retention	$V_{DR}$	$\overline{CS1-4} \geq V_{CC} - 0.2V$	2.0	-	-	V
Data Retention Current	$I_{CCDR}$	$V_{CC} = 3.0V, \overline{CS1-4} \geq V_{CC} - 0.2V, V_{IN} > 0V$	-	-	3.0	mA
Chip Deselect to Data Retention	$t_{CDR}$	See Retention Waveform	0	-	-	ns
Operation Recovery Time	$t_R$	See Retention Waveform	$t_{RC}$	-	-	ns

**AC Test Conditions**

- \*Input pulse levels: 0.0V to 3.0V
- \*Input rise and fall times: 5 ns
- \*Input and Output timing reference levels: 1.5V
- \* $V_{CC} = 5V \pm 10\%$
- \*PUMA module is tested in 32 bit mode.

**Output Load**



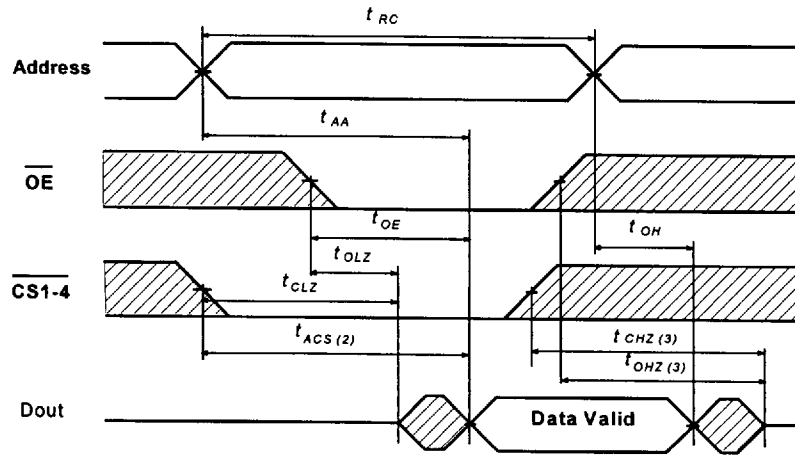
**AC OPERATING CONDITIONS****Read Cycle**

Parameter	Symbol	45		55		70		Units
		min	max	min	max	min	max	
Read Cycle Time	$t_{RC}$	45	-	55	-	70	-	ns
Address Access Time	$t_{AA}$	-	45	-	55	-	70	ns
Chip Select Access Time <sup>(2)</sup>	$t_{ACS}$	-	45	-	55	-	70	ns
Output Enable to Output Valid	$t_{OE}$	-	25	-	30	-	40	ns
Output Hold from Address Change	$t_{OH}$	5	-	5	-	5	-	ns
Chip Selection to Output in Low Z	$t_{CLZ}$	5	-	5	-	5	-	ns
Output Enable to Output in Low Z	$t_{OLZ}$	0	-	0	-	0	-	ns
Chip Deselection to Output in High Z <sup>(3)</sup>	$t_{CHZ}$	0	20	0	25	0	30	ns
Output Disable to Output in High Z <sup>(3)</sup>	$t_{OHZ}$	0	25	0	30	0	35	ns

**Write Cycle**

Parameter	Symbol	45		55		70		Unit
		min	max	min	max	min	max	
Write Cycle Time	$t_{WC}$	45	-	55	-	70	-	ns
Chip Selection to End of Write	$t_{CW}$	40	-	45	-	55	-	ns
Address Valid to End of Write	$t_{AW}$	40	-	45	-	55	-	ns
Address Setup Time	$t_{AS}$	0	-	0	-	0	-	ns
Write Pulse Width	$t_{WP}$	35	-	40	-	50	-	ns
Write Recovery Time	$t_{WR}$	3	-	3	-	3	-	ns
Write to Output in High Z	$t_{WHZ}$	0	20	0	25	0	30	ns
Data to Write Time Overlap	$t_{DW}$	20	-	25	-	30	-	ns
Data Hold from Write Time	$t_{DH}$	0	-	0	-	0	-	ns
Output Active from End of Write	$t_{OW}$	5	-	5	-	5	-	ns

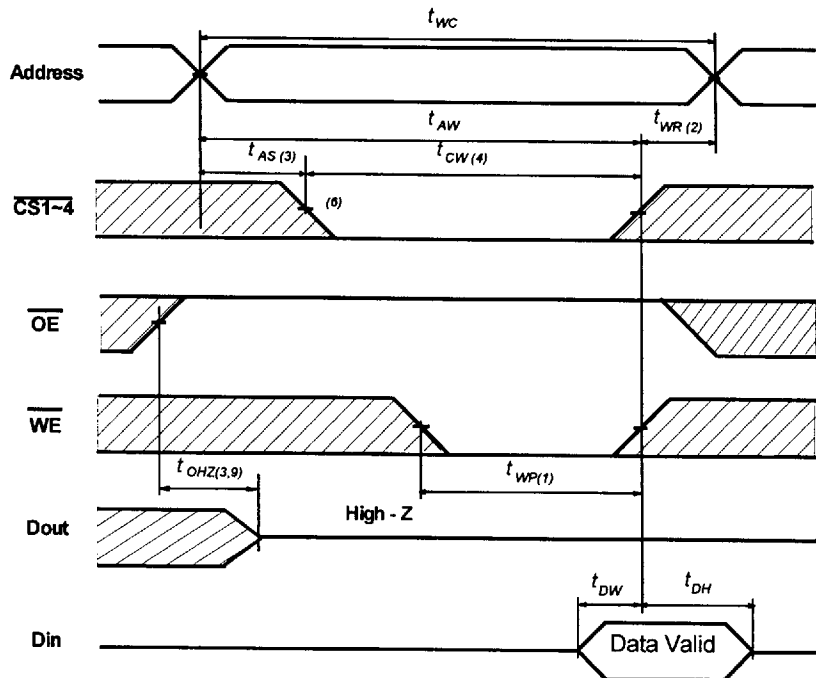
**Read Cycle Timing Waveform<sup>(1-3)</sup>**



**Notes:**

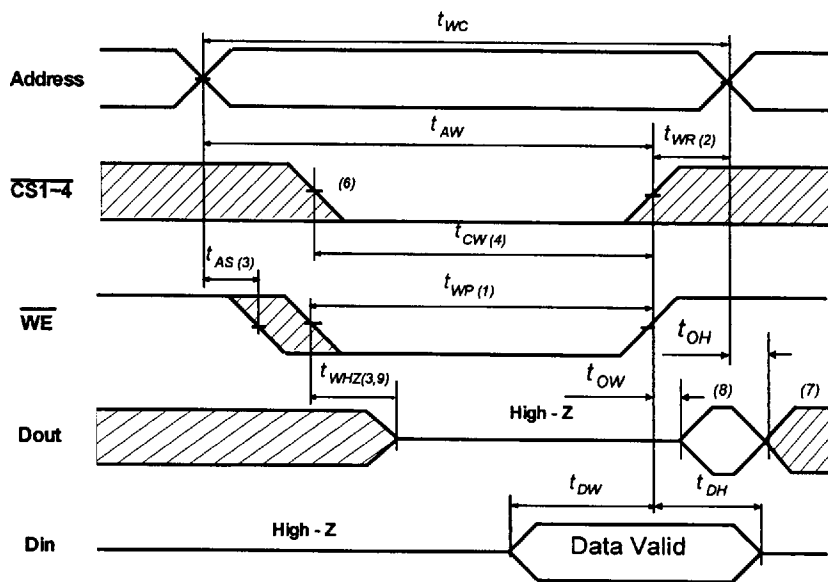
- (1) During the Read Cycle,  $\overline{WE}$  is high for the PUMA 67S4000 module and  $\overline{WE1-4}$  are high for the PUMA 67S4000A module.
- (2) Address valid prior to or coincident with  $\overline{CS1-4}$  transition Low.
- (3)  $t_{CHZ}$  and  $t_{OHZ}$  are defined as the time at which the outputs achieve the open circuit conditions and are not referenced to output voltage levels. These parameters are sampled and not 100% tested.

**Write Cycle No.1 Timing Waveform**



Note: On the PUMA 67S4000A,  $\overline{WE}$  refers to  $\overline{WE1-4}$ .

**Write Cycle No.2 Timing Waveform**



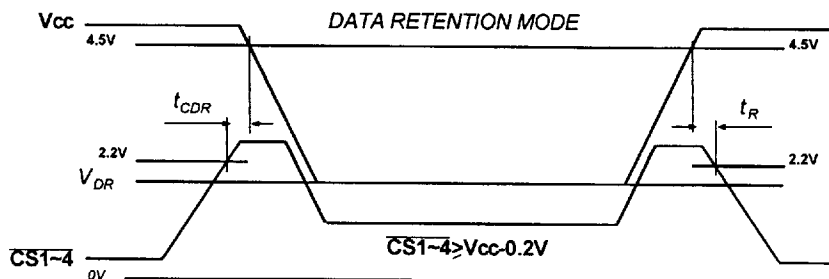
Note: On the PUMA 67S4000A,  $\overline{WE}$  refers to  $\overline{WE1\sim4}$ .

**AC Characteristics Notes**

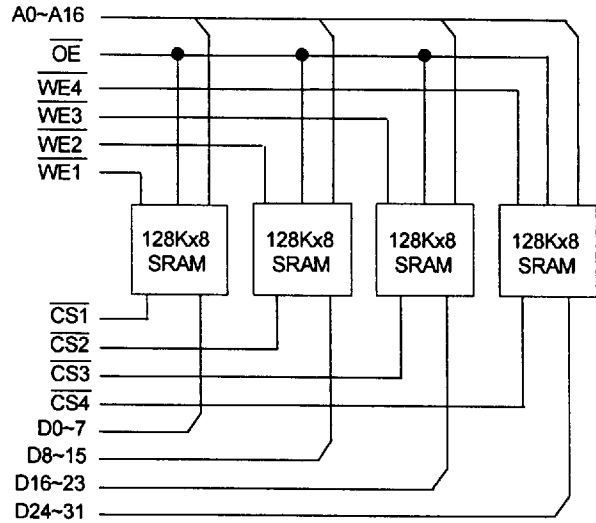
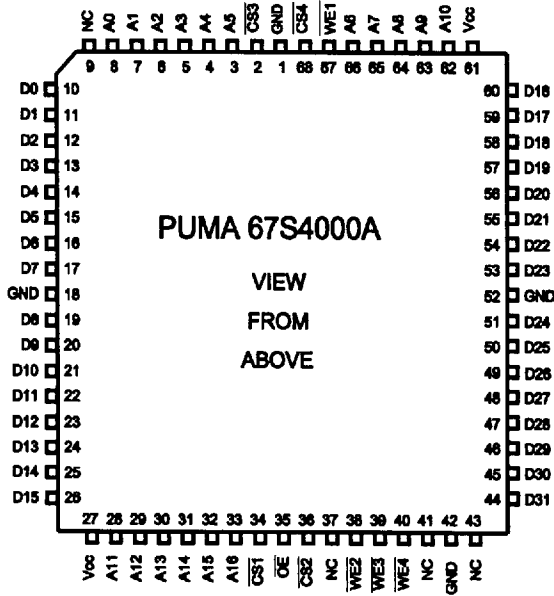
- (1) A write occurs during the overlap ( $t_{WP}$ ) of a low  $\overline{CS}$  and a low  $\overline{WE}$ .
- (2)  $t_{WR}$  is measured from the earlier of  $\overline{CS}$  or  $\overline{WE}$  going high to the end of write cycle.
- (3) During this period, I/O pins are in the output state. Input signals out of phase must not be applied.
- (4) If the  $\overline{CS}$  low transition occurs simultaneously with the  $\overline{WE}$  low transition or after the  $\overline{WE}$  low transition, outputs remain in a high impedance state.
- (5)  $\overline{OE}$  is continuously low. ( $\overline{OE}=V_{IL}$ )
- (6)  $D_{OUT}$  is in the same phase as written data of this write cycle.
- (7)  $D_{OUT}$  is the read data of next address.
- (8) If  $\overline{CS}$  is low during this period, I/O pins are in the output state. Input signals out of phase must not be applied.
- (9)  $t_{WHZ}$  and  $t_{OHZ}$  are defined as the time at which the outputs achieve the open circuit conditions and are not referenced to output voltage levels. These parameters are sampled and not 100% tested.

$\overline{CS}$  refers to  $\overline{CS1\sim4}$ .  $\overline{WE}$  above refers to  $\overline{WE}$  on the PUMA 67S4000 and  $\overline{WE1\sim4}$  on the PUMA 67S4000A

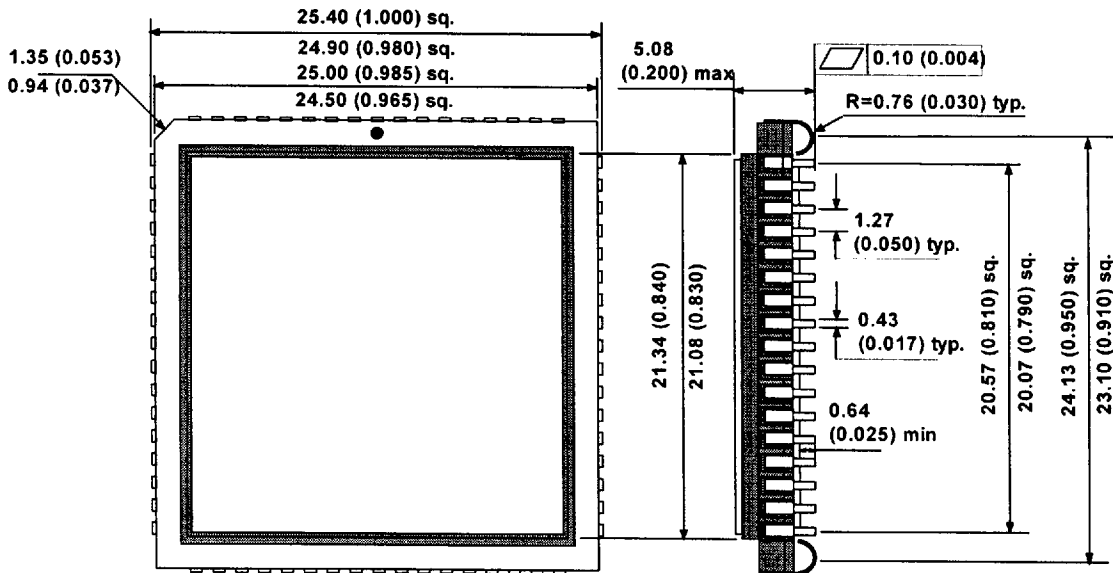
**Low  $V_{CC}$  Data Retention Timing Waveform**



Pin Definition version "A" Block Diagram version "A"



Package Details Dimensions in mm(inches)



**SCREENING****Military Screening Procedure**

MultiChip Screening Flow for high reliability product is in accordance with Mil-883 method 5004 .

<b>MB MULTICHIP MODULE SCREENING FLOW</b>		
<b>SCREEN</b>	<b>TEST METHOD</b>	<b>LEVEL</b>
<b>Visual and Mechanical</b> Internal visual Temperature cycle Constant acceleration	2010 Condition B or manufacturers equivalent 1010 Condition C (10 Cycles, -65°C to +150°C) 2001 Condition B (Y1 & Y2) (10,000g)	100% 100% 100%
<b>Burn-In</b> Pre-Burn-in electrical Burn-in	Per applicable device specifications at $T_A = +25^\circ\text{C}$ $T_A = +125^\circ\text{C}$ , 160hrs minimum.	100% 100%
<b>Final Electrical Tests</b> Static (DC)  Functional  Switching (AC)	Per applicable Device Specification a) @ $T_A = +25^\circ\text{C}$ and power supply extremes b) @ temperature and power supply extremes a) @ $T_A = +25^\circ\text{C}$ and power supply extremes b) @ temperature and power supply extremes a) @ $T_A = +25^\circ\text{C}$ and power supply extremes b) @ temperature and power supply extremes	100% 100% 100% 100% 100% 100%
<b>Percent Defective allowable (PDA)</b>	Calculated at post-burn-in at $T_A = +25^\circ\text{C}$	10%
<b>Hermeticity</b> Fine Gross	1014 Condition A Condition C	100% 100%
<b>Quality Conformance</b>	Per applicable Device Specification	Sample
<b>External Visual</b>	2009 Per vendor or customer specification	100%



**Ordering Information**

**PUMA 67S4000ALMB-45**

